FAIRCHILD BEMICONDUCTOR

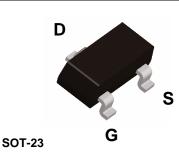
BSS138 N-Channel Logic Level Enhancement Mode Field Effect Transistor

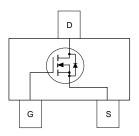
General Description

These N-Channel enhancement mode field effect transistors are produced using Fairchild's proprietary, high cell density, DMOS technology. These products have been designed to minimize on-state resistance while provide rugged, reliable, and fast switching performance. These products are particularly suited for low voltage, low current applications such as small servo motor control, power MOSFET gate drivers, and other switching applications.

Features

- 0.22 A, 50 V. $R_{DS(ON)}$ = 3.50 @ V_{GS} = 10 V $R_{DS(ON)}$ = 6.00 @ V_{GS} = 4.5 V
- High density cell design for extremely low R_{DS(ON)}
- Rugged and Reliable
- Compact industry standard SOT-23 surface mount package





Absolute Maximum Ratings T_A=25°C unless otherwise noted

Symbol	Parameter			Ratings	Units
V _{DSS}	Drain-Source	e Voltage	50	V	
V _{GSS}	Gate-Source	Voltage		±20	V
ID	Drain Currer	t – Continuous	(Note 1)	0.22	A
		– Pulsed		0.88	
P _D	Maximum Po	ower Dissipation	(Note 1)	0.36	W
	Derate Abov	e 25°C		2.8	mW/°C
T_J, T_{STG}	Operating and Storage Junction Temperature Range			-55 to +150	°C
TL	Maximum Lead Temperature for Soldering Purposes, 1/16" from Case for 10 Seconds			300	°C
Therma	I Charact	eristics			
$R_{ ext{ hetaJA}}$	Thermal Resistance, Junction-to-Ambient (Note 1)			350 °(
Packag	e Marking	g and Ordering	Information		·
Device Marking		Device	Reel Size	Tape width	Quantity
SS		BSS138	7"	8mm	3000 units

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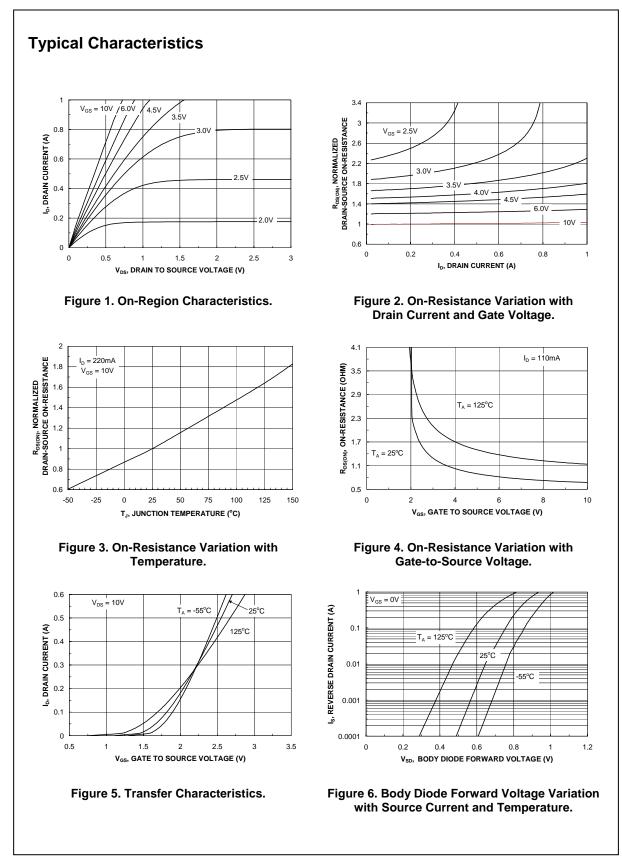
BSS138 Rev C(W)

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50 0.8 0.2 0.12	72 1.3 -2 0.7 1.0 1.1 0.5 27	0.5 5 100 ±100 1.5 3.5 6.0 5.8	V mV/°C μA nA nA nA V mV/°C Ω A S
0.8	1.3 -2 0.7 1.0 1.1 0.5	5 100 ±100 1.5 3.5 6.0	mV/°C μA μA nA NA V mV/°C Ω A
0.2	1.3 -2 0.7 1.0 1.1 0.5	5 100 ±100 1.5 3.5 6.0	μA μA nA nA V mV/°C Ω A
0.2	-2 0.7 1.0 1.1 0.5	5 100 ±100 1.5 3.5 6.0	μΑ nA nA V mV/°C Ω A
0.2	-2 0.7 1.0 1.1 0.5	100 ±100 1.5 3.5 6.0	nA nA W mV/°C Ω A
0.2	-2 0.7 1.0 1.1 0.5	±100 1.5 3.5 6.0	nA V mV/°C Ω A
0.2	-2 0.7 1.0 1.1 0.5	1.5 3.5 6.0	V mV/°C Ω A
0.2	-2 0.7 1.0 1.1 0.5	3.5 6.0	mV/°C Ω Α
0.2	-2 0.7 1.0 1.1 0.5	3.5 6.0	mV/°C Ω Α
-	0.7 1.0 1.1 0.5	6.0	Ω A
-	1.0 1.1 0.5	6.0	A
-	1.1 0.5		
-	0.5		
-		<u> </u>	
	27	·	·
	27		
		1	pF
	13	-	pF
	6	-	pF
	9		Ω
		4	1
	2.5	5	ns
	9	18	ns
	20	36	ns
	7	14	ns
	1.7	2.4	nC
	0.1		nC
	0.4		nC
		0.22	Α
	0.8	1.4	V
	2 is define	9 20 7 1.7 0.1 0.4	9 18 20 36 7 14 1.7 2.4 0.1 0.4 0.22 0.22

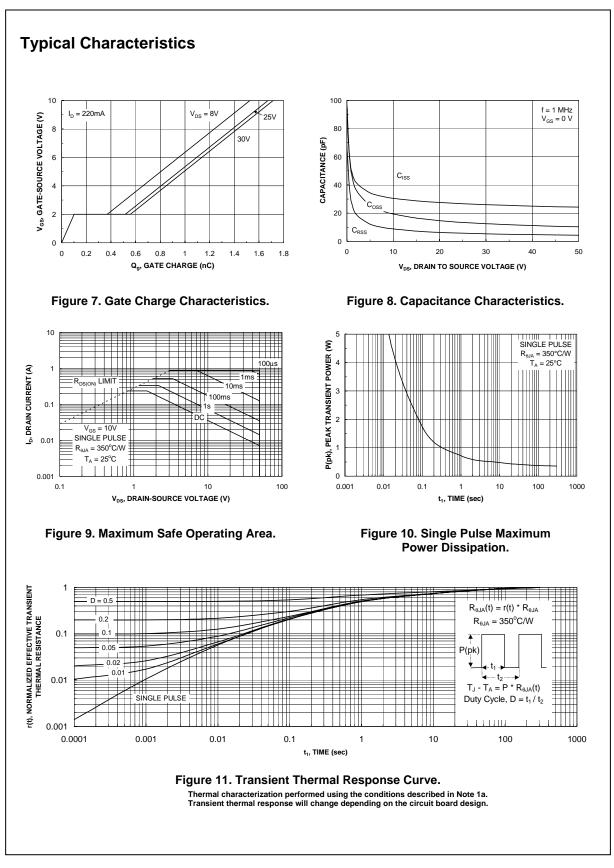
Scale 1 : 1 on letter size paper

2. Pulse Test: Pulse Width $\leq 300~\mu s,~\text{Duty}~\text{Cycle} \leq 2.0\%$



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		Rev. I1

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